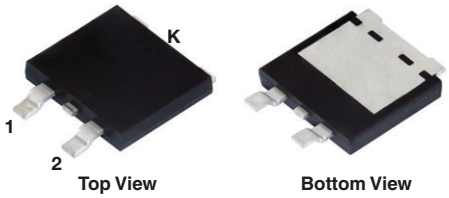
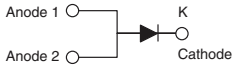
Hyperfast Rectifier, 16 A FRED Pt®

eSMP® Series
SMPD (TO-263AC)





LINKS TO ADDITIONAL RESOURCES

3D Models

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	16 A
V_R	600 V
V_F at I_F (T_J = 150 °C)	1.24 V
t_{rr}	30 ns
T_J max.	175 °C
Package	SMPD (TO-263AC)
Circuit configuration	Single

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE
RoHS COMPLIANT
HALOGEN FREE

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)
Molding compound meets UL 94 V-0 flammability rating
Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$ (1)	T_C = 127 °C	16	A
Non-repetitive peak surge current	I_{FSM}	T_J = 25 °C, 10 ms sine pulse	160	

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	I_R = 100 μA	600	-	-	V
Forward voltage	V_F	I_F = 16 A	-	1.65	2.15	
		I_F = 16 A, T_J = 150 °C	-	1.24	1.65	
Reverse leakage current	I_R	V_R = V_R rated	-	-	20	μA
		T_J = 150 °C, V_R = V_R rated	-	-	500	
Junction capacitance	C_T	V_R = 600 V	-	16	-	pF

Note
(1) Mounted on infinite heatsink

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DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNITS**
Reverse recovery time	t_{rr}	I_F = 1 A, dI_F/dt = 50 A/μs, V_R = 30 V		-	30	-	ns
		I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A		-	-	30	
		T_J = 25 °C	I_F = 16 A, dI_F/dt = 500 A/μs, V_R = 400 V	-	43	-	
		T_J = 125 °C		-	92	-	
Peak recovery current	I_{RRM}	T_J = 25 °C		-	7.7	-	A
		T_J = 125 °C		-	13.8	-	
Reverse recovery charge	Q_{rr}	T_J = 25 °C		-	150	-	μC
		T_J = 125 °C		-	600	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNITS**
Maximum junction and storage temperature range	T_J, T_{Stg}		-55	-	+175	°C
Thermal resistance, junction to mount	R_{thJM}		-	1.2	1.7	°C/W
Approximate weight			0.55			g
Marking device		Case style SMPD (TO-263AC)	16EDH06			

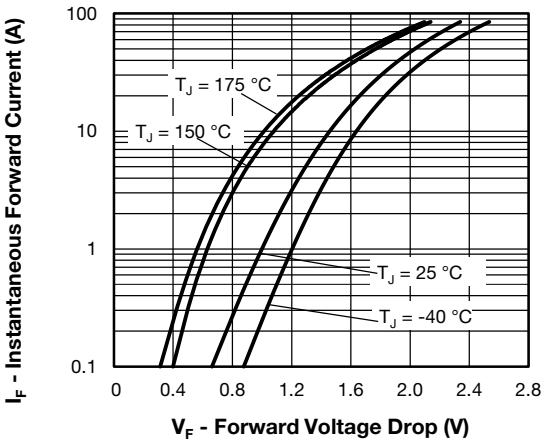

Fig. 1 - Typical Forward Voltage Drop Characteristics

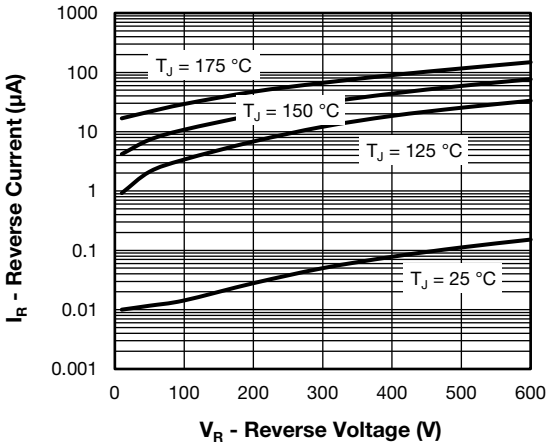

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

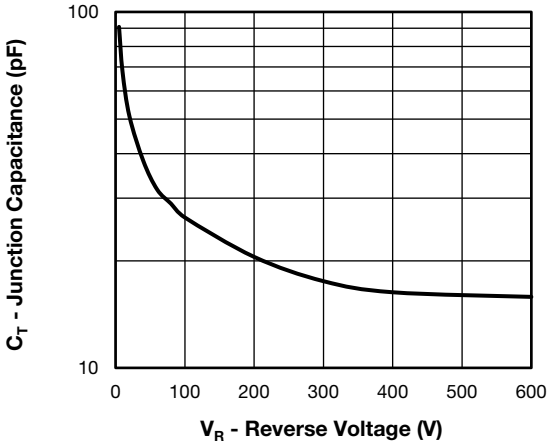

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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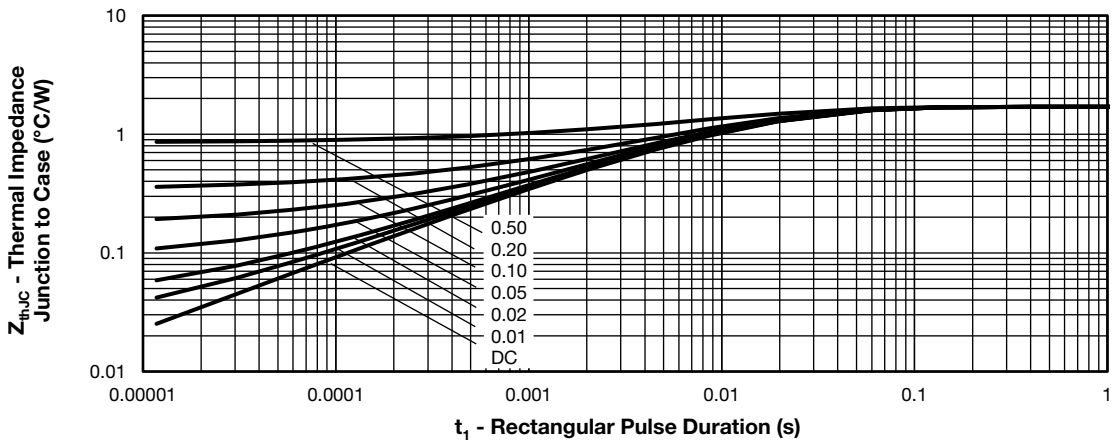

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

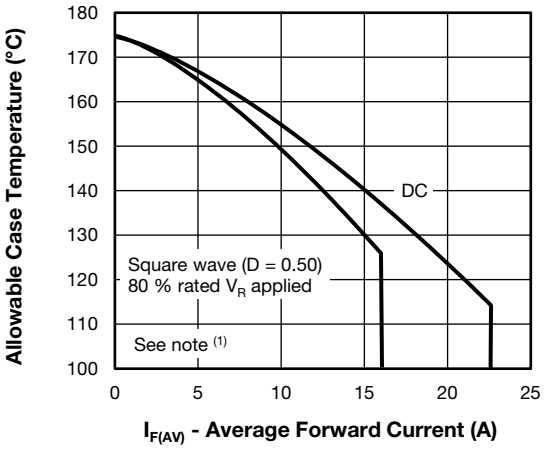

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

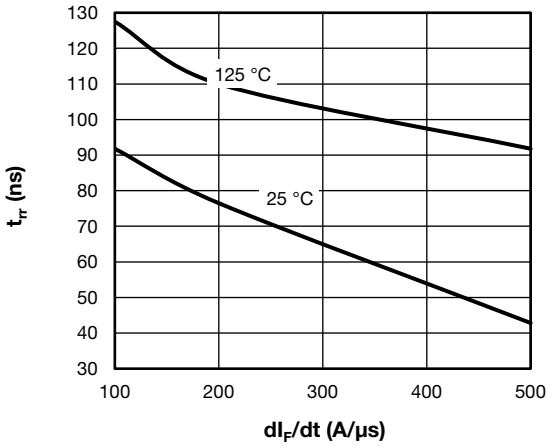

Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 5);
Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

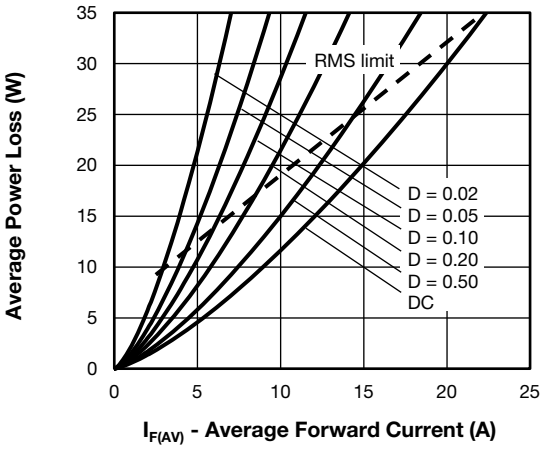

Fig. 7 - Forward Power Loss Characteristics

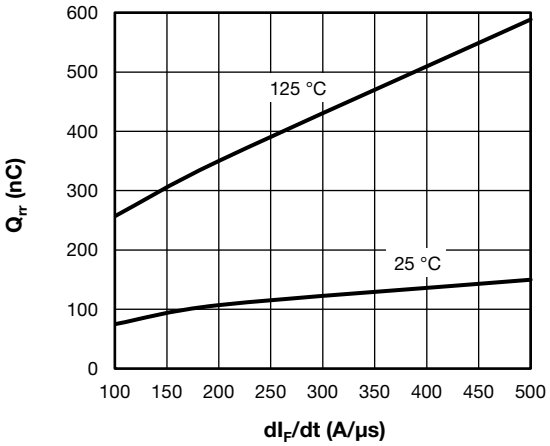

Fig. 8 - Typical Stored Charge vs. dI_F/dt

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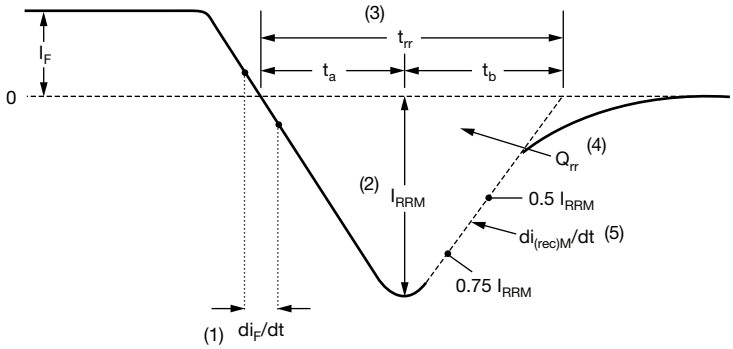

(1) di_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code	VS-	16	E	D	H	06	H	M3
	1	2	3	4	5	6	7	8

1 - Vishay Semiconductors product
2 - Current rating (16 A)
3 - Circuit configuration:
E = single die
4 - D = SMPD package
5 - Process type,
H = hyperfast recovery
6 - Voltage code (06 = 600 V)
7 - H = AEC-Q101 qualified
8 - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	**QUANTITY PER REEL**	**MINIMUM ORDER QUANTITY**	**PACKAGING DESCRIPTION**
VS-16EDH06HM3/I [(1)]	2000	2000	13" diameter plastic tape and reel

Note
[(1)] AEC-Q101 qualified

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95604
Part marking information	www.vishay.com/doc?95566
Packaging information	www.vishay.com/doc?88869

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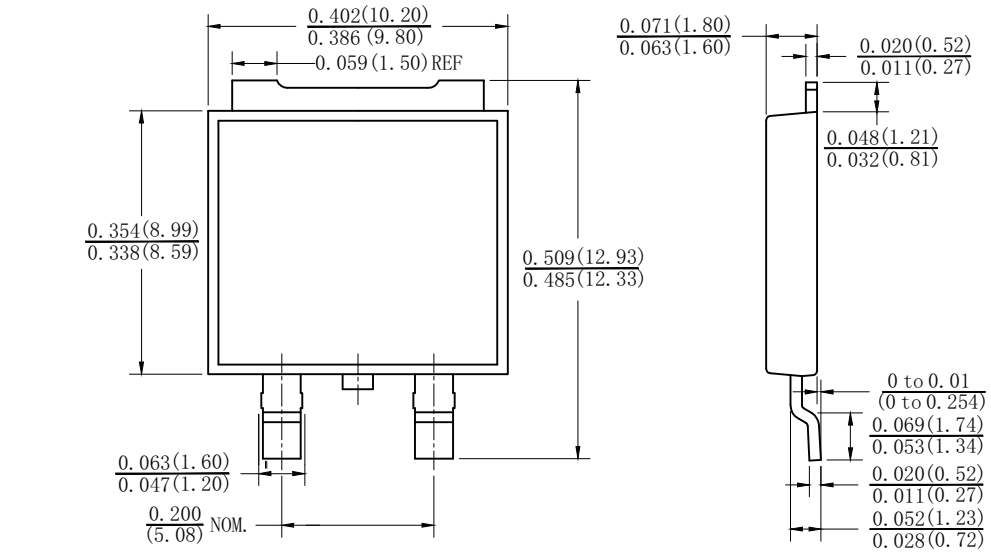
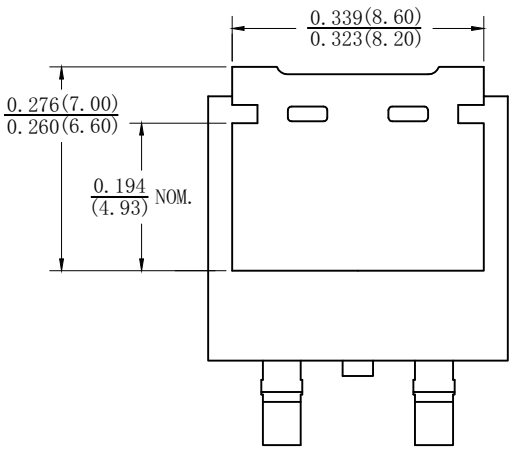
TO-263AC (SMPD)

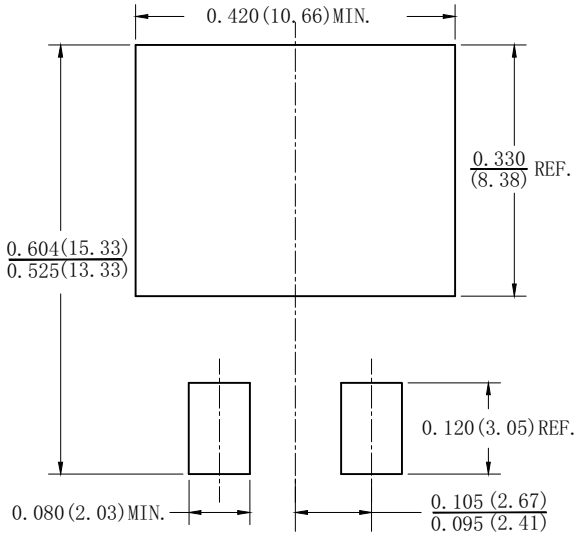
DIMENSIONS in inches (millimeters)

TO-263AC (SMPD)





Mounting Pad Layout



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